

Electronic Information Disclosure Statement

HIGH PERFORMANCE VARACTOR DIODES

Application: 10/728,140

Confirmation:

Applicant(s): Douglas Coolbaugh

Docket
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Examiner: H. Lee

search string: (3396317 or 3634738 or 3636420 or 3638300 or 3706128 or 3860945 or 4226648 or 4373166 or 4827319).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
<i>Lee</i>	P01	3396317	1968-08-06	*3396317*	Vendelin	317	234
	P02	3634738	1972-01-11	*3634738*	Leith et al.	317	234
	P03	3636420	1972-01-18	*3636420*	Vendelin	317	234
	P04	3638300	1972-02-01	*3638300*	Foxhall et al.	29	589
	P05	3706128	1972-12-19	*3706128*	Heer	29	578
	P06	3860945	1975-01-14	*3860945*	Dawson	357	14
	P07	4226648	1980-10-07	*4226648*	Goodwin et al.	148	175
	P08	4373166	1983-02-08	*4373166*	Bergeron et al.	357	15
<i>Lee</i>	P09	4827319	1989-05-02	*4827319*	Pavlidis et al.	357	14

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Remarks

(Remarks are not for responding to an office action.)

Lee Archambaul et al., Patent No. EP0231700A, Issued 12/19/1986, France Kannam et al., "Design Considerations of Hyperabrupt Varactor Diodes", IEEE Transactions on Electron Devices, Vol. 1, No. 2, 2, February 1971.

Signature

Examiner Name	Date
<i>Karin Ming Lee</i>	<i>6/24/2004</i>